



## Si786 Demonstration Board

#### **FEATURES**

- 5- and 3.3-V Step-Down Synchronous Converters
- Less than 500-μA Quiescent Current
- 25-µA Shutdown Current
- 5.5- to 30-V Input Operating Range

The Si786 Dual-Output Power-Supply Controller for Notebook Computers is a system level integration of two step-down controllers, micropower 5- and 3.3-V linear regulators, and two comparators. The controllers perform high efficiency conversion of the battery pack energy (typically 12 V) or the output of an ac-to-dc wall converter (typically 18- to 24-V $_{\rm DC}$ ) to 5- and 3.3-V system supply voltages. The micropower linear regulator can be used to keep power management and back-up circuitry alive during the shutdown of the step-down converters. The comparators can be biased at any voltage, simplifying battery monitoring or providing sufficient voltage to enhance the gate of a low on-resistance n-channel FET used

in switching power to different zones in the system.

On the Demo Board, the Si786 is configured as a complete system, ready for operation. It takes 5.5- to 30-V in, and produces regulated 5 V at any current from no load to 3 A, and 3.3 V out at any current from no load to 3 A. Included in this document are the Bill of Materials, Demo Board Schematic, and PCB layout

The demonstration board layout is available in Gerber file format. Please contact your Vishay Siliconix sales representative or distributor for a copy.

#### **ORDERING INFORMATION: PART NUMBER Si786DBDB**

#### **POWER-UP CHECK LIST**

- Start by setting the control switches located in the bottom right corner of the Demo Board. Set the top switch to the left, setting the switching frequency to 200 kHz (to the right is 300 kHz). Set the second switch down to the right, turning the 5-V converter on (to the left is off). Set the third switch down to the right, turning the 3.3-V converter on (to the left is off). Set the bottom switch to the right, allowing the PWM to operate (to the left is shutdown).
- 2. Attach an electronic load set in resistive mode to the 3.3-V output pins. Set the current to 100 mA. Alternatively, you can use a resistor of value 33  $\Omega$ , 1 W.
- 3. Attach an electronic load set in resistive mode to the 5-V output pins. Set the current to 100 mA. Alternatively, you can use a resistor of value 50  $\Omega$ , 1 W.
- 4. Attach a 10-V supply and ground to the pins on the top side of the board. It is best to use a separate wire from the supply's ground to each of the Demo Board's ground pins, because of the high currents at low input voltages.
- 5. Take an oscilloscope probe, and place the ground on the 5-V GND pin, and the probe on the 5-V pin. Set the vertical scale for this channel at ac coupled at 50 mV/div. Take a second probe, and place the ground on the 5-V GND pin, and the probe on pin 17 (LX<sub>5</sub>) of the Si786. Set this channel at dc coupled 2 V/div. Set the time base at 200 μsec/div.
- Leave the probes in place. Change the scale on the second probe (the one attached to pin 17) to 10 V/div, and

- the time base to 500 nsec/div. Set the 5-V output current on the electronic load to 1 A. Set the input power supply to 16 V. Alternatively, *first turn off the input power supply*, and replace the 50-W resistor with a  $5-\Omega$ , 10-W resistor, and then turn the input power supply back on, setting it to 16 V.
- 7. This step should be performed only if an electronic load is being used. Set the input voltage to 15 V. Remove the second probe (the one attached to pin 17 of the Si786), or turn off the channel displaying it. Place a current probe around the wire leading from the 5-V output to the electronic load, and set the oscilloscope and amplifier so that it will display approximately 2 A/div. Set the oscilloscope time base back to 200 μsec/div. Set the 3.3-V electronic load to have a constant 1-A load. Now set up the 5-V electronic load so that it cycles between 100 mA and 3 A at approximately 1 kHz (1 msec period).
- 8. This step should be performed only if an electronic load is being used. Set the 5-V electronic load back to a constant 1-A current. Remove the voltage probe from the 5-V output. Move the ground of the probe onto the GND pin of the 3.3-V output, and the probe onto the 3.3-V output pin. Remove the current probe from the 5-V output wire, and place it around the wire leading from the 3.3-V output to the electronic load. Now set up the 3.3-V electronic load so that it cycles between 100 mA and 3 A at approximately 1 kHz (1 msec period).

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### **PCB LAYOUT**

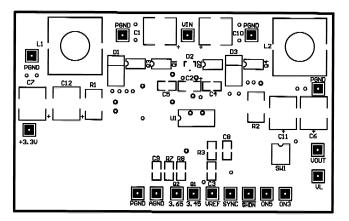


Figure 1. Top Silkscreen

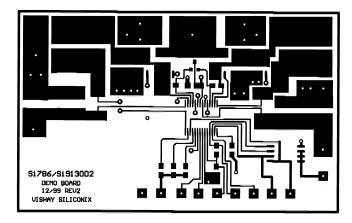


Figure 2. Top Layer

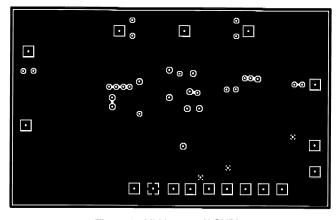


Figure 3. Mid-Layer 1 (AGND)

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### **PCB LAYOUT**

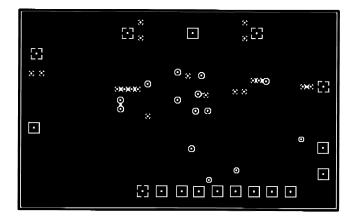


Figure 4. Mid-Layer 2 (PGND)

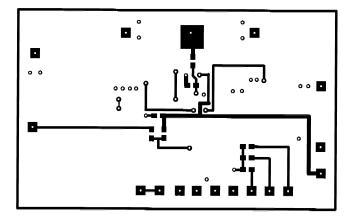


Figure 5. Bottom Layer

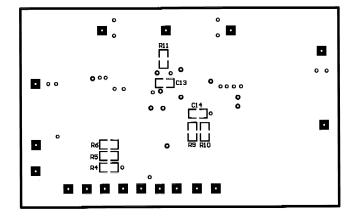
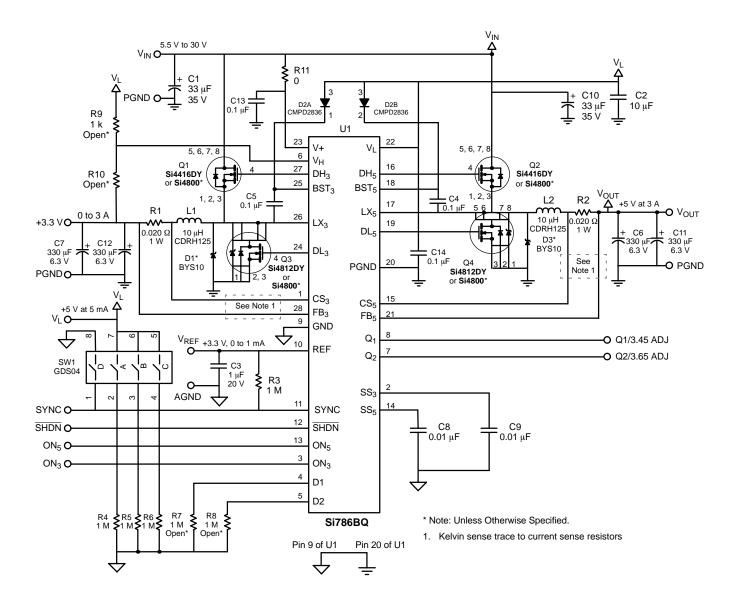


Figure 6. Bottom Silkscreen

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#### **APPLICATION CIRCUIT**



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| BILL-OF-MATERIALS: Si786, DEMO BOARD 2 |          |                   |              |  |           |                         |                       |
|--|----------|-------------------|--------------|--|-----------|-------------------------|-----------------------|
| Item                                   | Qty      | Designator        | Part Type    | Description                                | Footprint | Vendor Part#            | Manufacturer          |
|  |          |                   |              |  | ,         |                         | 1                     |
| 1                                      | 2        | R1, R2            | 0.02 Ω       | Resistor, 1 W, 1%                          | WSL-2512  | WSL-2512                | Vishay Dale           |
| 2                                      | 6        | R3, R4, R5, R6    | 1 ΜΩ         | Resistor, <sup>1</sup> / <sub>8</sub> , 1% | WSL-2512  | CRCW08051004FRT1        | Vishay Dale           |
| 3                                      | 3        | R7, R8, R9        | Open         | Resistor, <sup>1</sup> / <sub>8</sub> , 1% | 0805      | N.U.                    |                       |
| 4                                      | 1        | R10               | Open         | Resistor, <sup>1</sup> / <sub>8</sub> , 1% | 0805      | N.U.                    |                       |
| 5                                      | 1        | R11               | 0            | Resistor, <sup>1</sup> / <sub>8</sub> , 1% | 0805      | CRCW08050000FRT1        | Vishay Dale           |
|  |          |                   |              |  |           |                         |                       |
| 6                                      | 2        | C1, C10           | 33 μF        | CAP, TAN, 35 V                             | 595D_R    | 595D336X0035R2T         | Vishay Sprague        |
| 7                                      | 1        | C2                | 10 μF        | CAP, CER, 6.3 V                            | 1206      | GRM42-6, X5R, 106K, 6.3 | Murata                |
| 8                                      | 1        | C3                | 1 μF         | CAP, CER, Z5U, 50 V, 10%                   | 0805      | VJ0805Y106KXAAT         | Vishay Vitramon       |
| 9                                      | 4        | C4, C5, C13, C14  | 0.1 μF       | CAP, CER, X7R, 50 V, 10%                   | 0805      | VJ0805Y104KXAAT         | Vishay Vitramon       |
| 10                                     | 4        | C6, C7, C11, C12  | 330 μF       | CAP, TAN, 6.3 V                            | 595D_D    | 595D337X06R3D2T         | Vishay Sprague        |
| 11                                     | 2        | C8, C9            | 0.01 μF      | CAP, CER, X7R, 50 V, 10%                   | 0805      | VJ0805Y103KXAAT         | Vishay Vitramon       |
|  |          |                   |              |  | •         |                         |                       |
| 12                                     | 2        | D1*, D3*          | BYS10-35     | Schottky Diode, 35 V                       | BYS10     | BYS10-35                | Vishay Telefunken     |
| 13                                     | 1        | D2                | CMPD2836     | Diode, Dual 1N4148                         | SOT-23    | CMPD2836                | Central Semiconductor |
|  | ı        |                   |              |  | J.        |                         |                       |
| 14                                     | 2        | L1, L2            | 10 μΗ        | 10 μH Inductor, 20%                        | CDRH125   | CDRH125-100             | Sumida                |
|  | <u> </u> |                   |              | ·  | ı         | l                       | I                     |
| 15                                     | 2        | Q1*, Q2*          | Si4416DY     | N-MOSFET                                   | SO-8      | Si4416DY                | Vishay Siliconix      |
| 16                                     | 2        | Q3*, Q4*          | Si4812DY     | N-MOSFET                                   | SO-8      | Si4812DY                | Vishay Siliconix      |
|  | ı        |                   | 1            |  |           |                         |                       |
| 17                                     | 1        | U1                | Si786/9130DB | Power IC                                   | SSOP-28   | Si9137                  | Vishay Siliconix      |
|  | <u> </u> |                   | <u> </u>     |  | 1         |                         | 1                     |
| 18                                     | 1        | SW1               | GDS04        | 4-POS SMT Switch                           | SW-SO8    | GDS04                   | Augat                 |
|  |          |                   |              |  |           |                         |                       |
| 19                                     | 17       | Power, GND and TP | Header       | 1-Pin Header                               | TP1       | Header                  | Multi-Source          |

\*Note: Use Si4800 for Q1 to Q4 with D1 and D3; or use Si4416DY for Q1 and Q2, Si4812DY for Q3 and Q4 without D1 and D3.